



**THE DATASHEET OF
RB150M-30GTR**



1. PRODUCT Schottky barrier Diode (Silicon Epitaxial Planer)
2. TYPE RB150M-30
3. APPLICATION General rectification
4. FEATURE Small power mold type (PMDU)
High reliability
Low VF
5. ABSOLUTE MAXIMUM RATING (Ta=25°C)

Reverse voltage(repetitive peak)	VRM	30 V
Reverse voltage(DC)	VR	30 V
Average rectified forward current (*1) Io		1.5 A
Forward current surge peak(60Hz·1cyc.)	IFSM	30 A
Junction temperature	TJ	150 °C
Storage temperature	Tstg	-40~150 °C

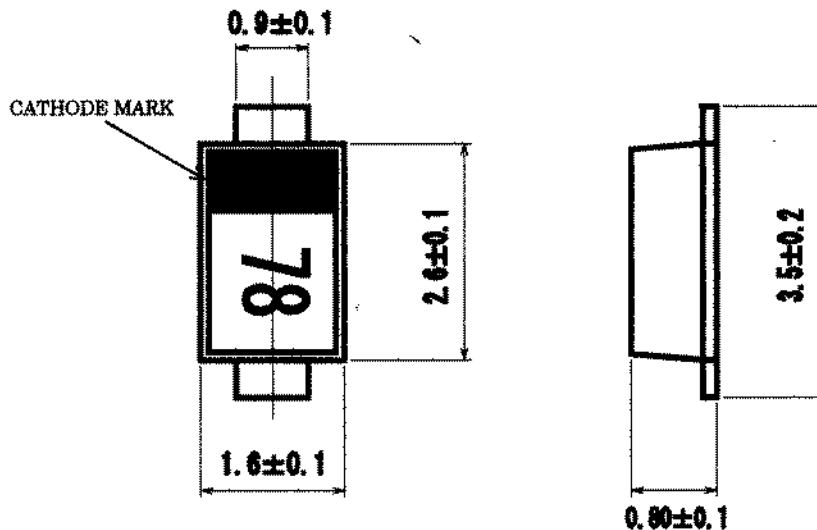
[(*1)Glass epoxy substrate at the time of assembler,
half sine wave at 180°C Tc=90°C max]

6. ELECTRICAL CHARACTERISTIC (Ta=25°C)

Characteristic	Symbol	Test condition	Standard	
			TYP.	MAX.
Forward voltage	VF1	IF= 0.5 A	0.39 V	0.46 V
	VF2	IF= 1.0 A	0.43 V	0.48 V
Reverse current	IR1	VR= 15 V	3.0 μA	20 μA
	IR2	VR= 30 V	9.0 μA	50 μA
Thermal resistance	Rth(j-a)	at mounted on epoxy board land pattern : 6*6mm	142.8 °C/W	-

* Please pay attention to static electricity when handling.

7. DIMENSION (UNIT:mm)



8. Mass per piece 10 mg/pcs







DESIGN	CHECK	APPROVAL	DATE:AUG.08.2002	SPECIFICATION No. : RB150M-30*ENG
			REV.A	ROHM CO., LTD.

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